

BUJ100LR

NPN power transistor

Rev. 02 — 29 July 2010

Product data sheet

1. Product profile

1.1 General description

High voltage, high speed, planar passivated NPN power switching transistor in a SOT54 (TO-92) 3 leads plastic package.

1.2 Features and benefits

- Fast switching
- High voltage capability of 700 V

1.3 Applications

- Compact fluorescent lamps (CFL)
- Inverters
- Electronic lighting ballasts
- Off-line self-oscillating power supplies

1.4 Quick reference data

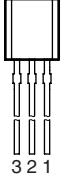
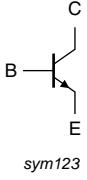
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_C	collector current	DC; see Figure 2	-	-	1	A
P_{tot}	total power dissipation	$T_{lead} \leq 25^\circ\text{C}$; see Figure 1	-	-	2.1	W
V_{CESM}	collector-emitter peak voltage	$V_{BE} = 0\text{ V}$	-	-	700	V
Static characteristics						
h_{FE}	DC current gain	$V_{CE} = 5\text{ V}$; $I_C = 0.8\text{ A}$; $T_{lead} = 25^\circ\text{C}$; see Figure 8 ; see Figure 9	5	7.5	20	



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base		
2	C	collector		
3	E	emitter	 3 2 1	 B C E sym123

SOT54 (TO-92)

3. Ordering information

Table 3. Ordering information

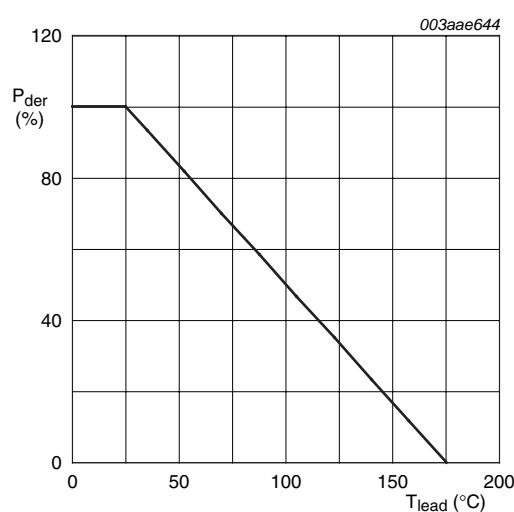
Type number	Package		Version
	Name	Description	
BUJ100LR	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

4. Limiting values

Table 4. Limiting values

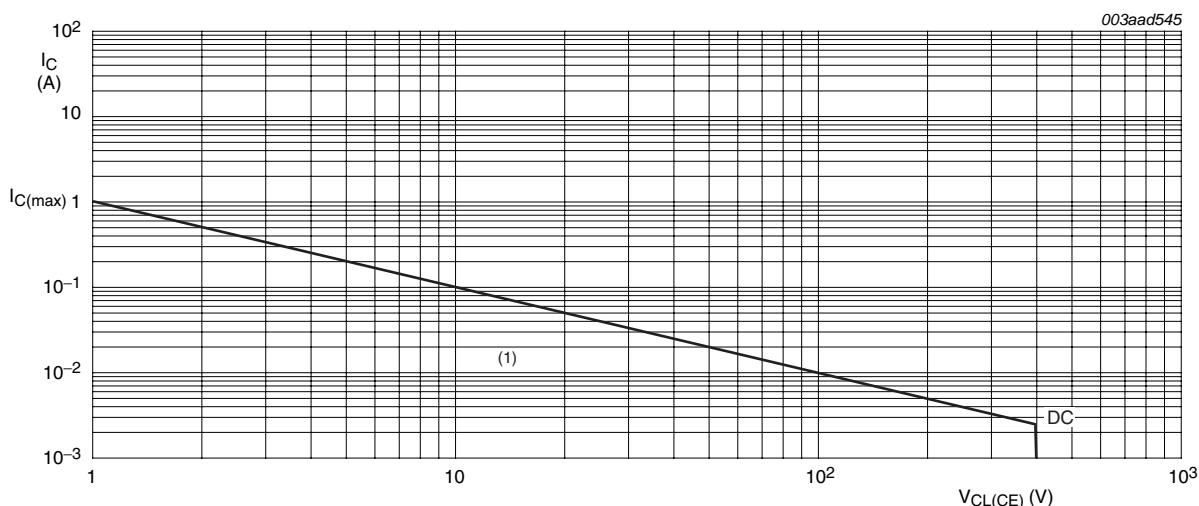
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CESM}	collector-emitter peak voltage	$V_{BE} = 0 \text{ V}$	-	700	V
V_{CBO}	collector-base voltage	$I_E = 0 \text{ A}$	-	700	V
V_{CEO}	collector-emitter voltage	$I_B = 0 \text{ A}$	-	400	V
I_C	collector current	DC; see Figure 2	-	1	A
I_{CM}	peak collector current		-	2	A
I_B	base current	DC	-	0.5	A
I_{BM}	peak base current		-	1	A
P_{tot}	total power dissipation	$T_{\text{lead}} \leq 25 \text{ }^{\circ}\text{C}$; see Figure 1	-	2.1	W
T_{stg}	storage temperature		-65	150	$^{\circ}\text{C}$
T_j	junction temperature		-	150	$^{\circ}\text{C}$
V_{EBO}	emitter-base voltage	$I_C = 0 \text{ A}$; $I(\text{Emitter}) = 10 \text{ mA}$	-	9	V



$$P_{der} = \frac{P_{tot}}{P_{tot}(25^{\circ}\text{C})} \times 100 \%$$

Fig 1. Normalized total power dissipation as a function of lead temperature



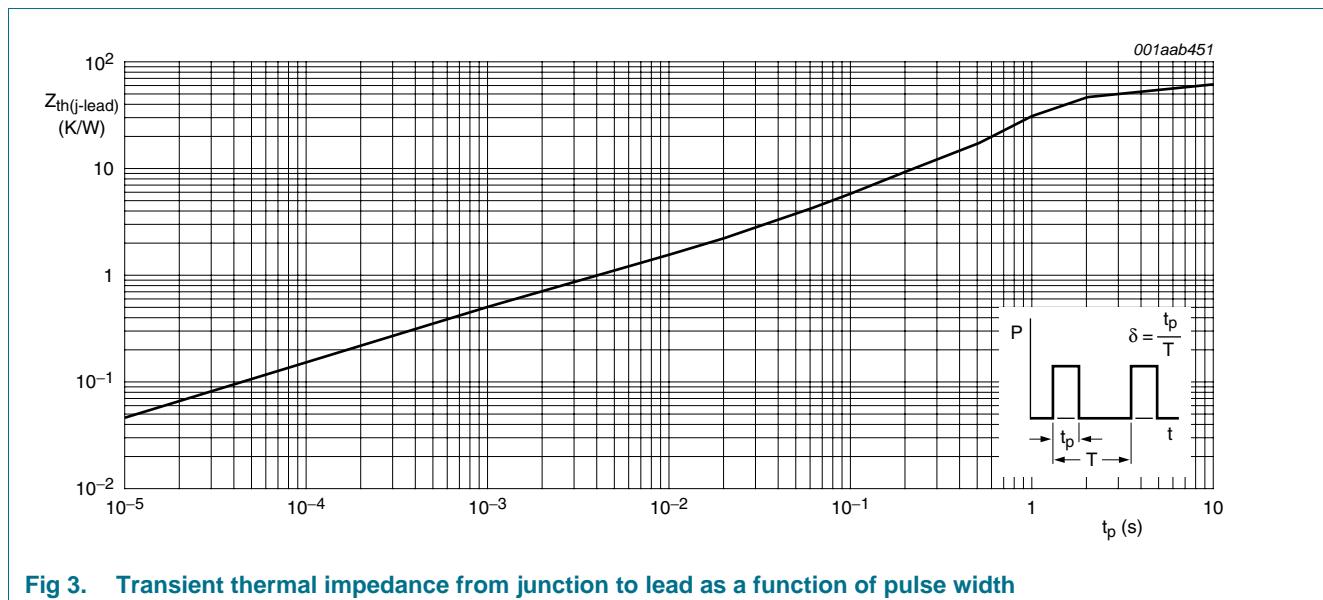
$T_{lead} \leq 25^{\circ}\text{C}$ (1) Region of permissible DC operation

Fig 2. Forward bias safe operating area

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	see Figure 3	-	-	60	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	printed-circuit board mounted; lead length 4 mm	-	150	-	K/W



6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
I_{CES}	collector-emitter cut-off current	$V_{BE} = 0 \text{ V}$; $V_{CE} = 700 \text{ V}$; $T_j = 125 \text{ }^\circ\text{C}$	-	-	5	mA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 9 \text{ V}$; $I_C = 0 \text{ A}$; $T_{lead} = 25 \text{ }^\circ\text{C}$	-	-	1	mA
V_{CEOsus}	collector-emitter sustaining voltage	$I_B = 0 \text{ A}$; $I_C = 1 \text{ mA}$; $L_C = 25 \text{ mH}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 4 ; see Figure 5	400	-	-	V
V_{CEsat}	collector-emitter saturation voltage	$I_C = 0.25 \text{ A}$; $I_B = 50 \text{ mA}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 6	-	0.2	0.5	V
		$I_C = 0.5 \text{ A}$; $I_B = 125 \text{ mA}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 6	-	0.3	1	V
		$I_C = 0.75 \text{ A}$; $I_B = 250 \text{ mA}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 6	-	0.4	1.5	V
V_{BESat}	base-emitter saturation voltage	$I_C = 0.25 \text{ A}$; $I_B = 50 \text{ mA}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 7	-	-	1	V
		$I_C = 0.5 \text{ A}$; $I_B = 125 \text{ mA}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 7	-	-	1.2	V
h_{FE}	DC current gain	$I_C = 0.5 \text{ mA}$; $V_{CE} = 2 \text{ V}$; $T_{lead} = 25 \text{ }^\circ\text{C}$	12	-	-	
		$I_C = 0.4 \text{ A}$; $V_{CE} = 5 \text{ V}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 8 ; see Figure 9	10	-	30	
		$I_C = 0.8 \text{ A}$; $V_{CE} = 5 \text{ V}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; see Figure 8 ; see Figure 9	5	7.5	20	
Dynamic characteristics						
t_f	fall time	$I_C = 1 \text{ A}$; $I_{Bon} = 200 \text{ mA}$; $V_{BB} = -5 \text{ V}$; $L_B = 1 \mu\text{H}$; $T_{lead} = 25 \text{ }^\circ\text{C}$; inductive load; see Figure 10 ; see Figure 11	-	80	-	ns

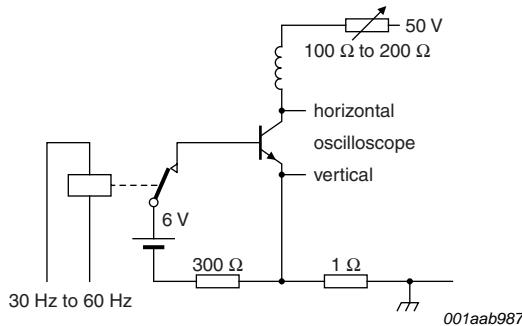


Fig 4. Test circuit for collector-emitter sustaining voltage

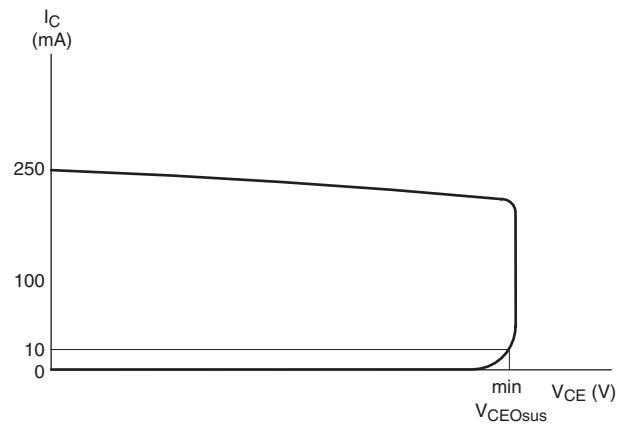
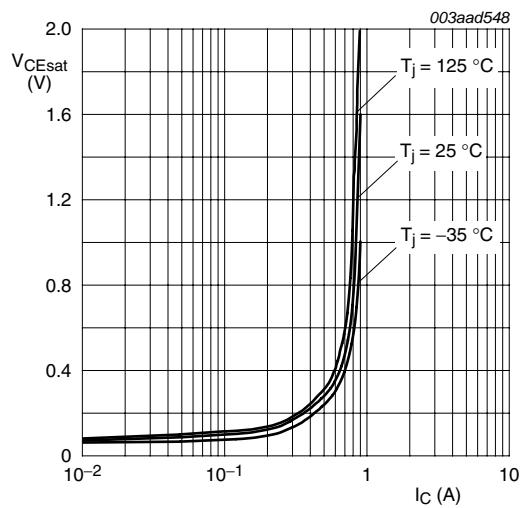
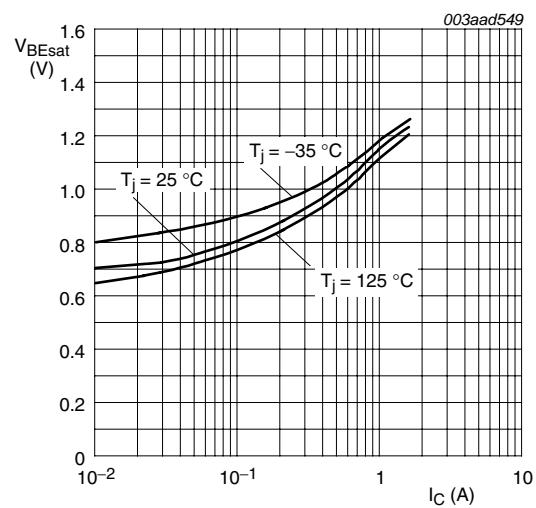


Fig 5. Oscilloscope display for collector-emitter sustaining voltage test waveform



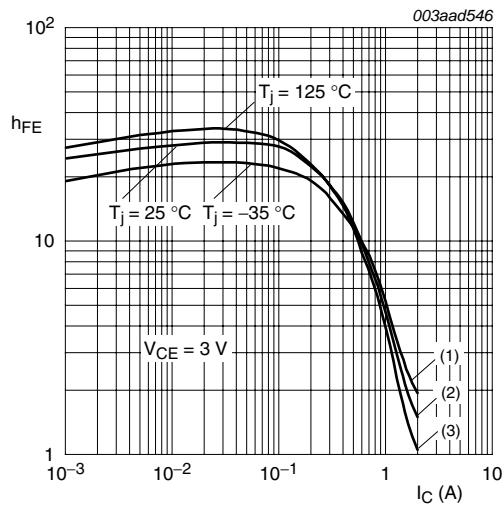
$$\frac{I_C}{I_B} = 5$$

Fig 6. Collector-emitter saturation voltage as a function of collector current; typical values



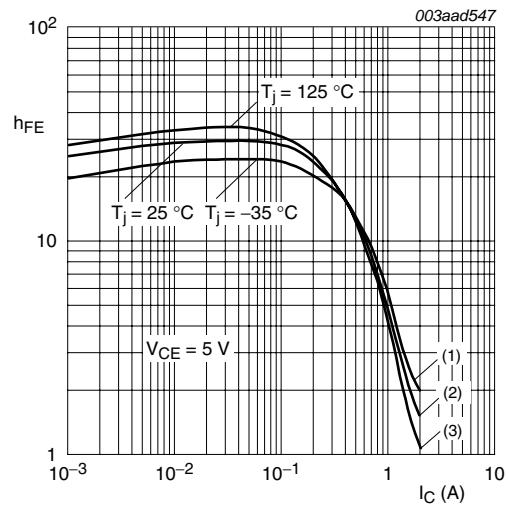
$$\frac{I_C}{I_B} = 5$$

Fig 7. Base-emitter saturation voltage as a function of collector current; typical values



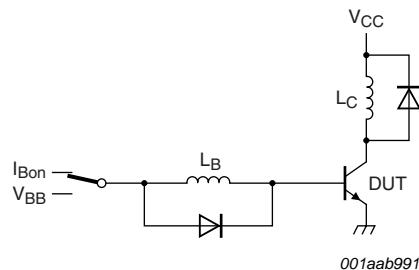
(1) $T_j = -35^\circ\text{C}$ (2) $T_j = 25^\circ\text{C}$ (3) $T_j = 125^\circ\text{C}$

Fig 8. DC current gain as a function of collector current; typical values



(1) $T_j = -35^\circ\text{C}$ (2) $T_j = 25^\circ\text{C}$ (3) $T_j = 125^\circ\text{C}$

Fig 9. DC current gain as a function of collector current; typical values



$V_{CC} = 300 \text{ V}$; $V_{BB} = -5 \text{ V}$; $L_C = 200 \mu\text{H}$; $L_B = 1 \mu\text{H}$

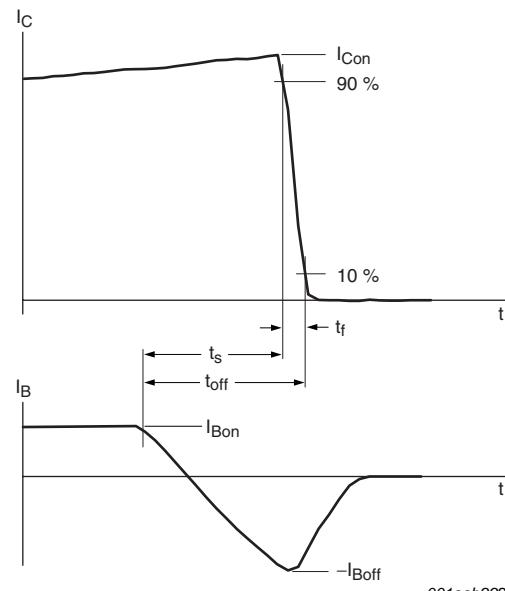


Fig 10. Test circuit for inductive load switching

Fig 11. Switching times waveforms for inductive load

7. Package outline

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

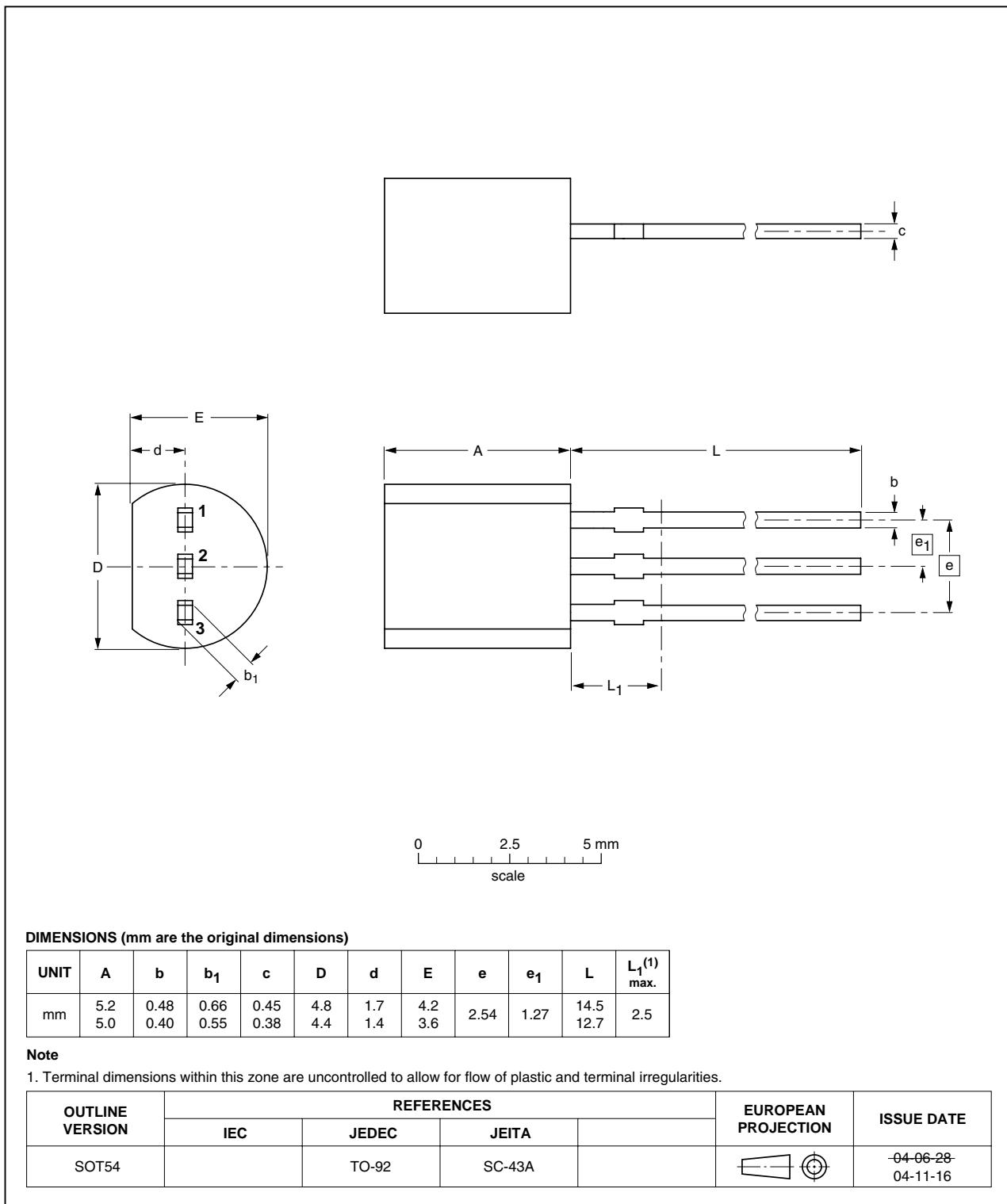


Fig 12. Package outline SOT54 (TO-92)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BUJ100LR v.2	20100729	Product data sheet	-	BUJ100LR v.1
Modifications:		• Various changes to content.		
BUJ100LR v.1	20090812	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

9.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

9.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on a weakness or default in the customer application/use or the application/use of customer's third party customer(s) (hereinafter both referred to as "Application"). It is customer's sole responsibility to check whether the NXP Semiconductors product is suitable and fit for the Application planned. Customer has to do all necessary testing for the Application in order to avoid a default of the Application and the product. NXP Semiconductors does not accept any liability in this respect.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding. Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

9.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Adelante, Bitport, Bitsound, CoolFlux, CoReUse, DESFire, EZ-HV, FabKey, GreenChip, HiPerSmart, HITAG, I²C-bus logo, ICODE, I-CODE, ITEC, Labelution, MIFARE, MIFARE Plus, MIFARE Ultralight, MoReUse, QLPAK, Silicon Tuner, SiliconMAX, SmartXA, STARplug, TOPFET, TrenchMOS, TriMedia and UCODE — are trademarks of NXP B.V.

HD Radio and **HD Radio** logo — are trademarks of iBiquity Digital Corporation.

10. Contact information

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

11. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	4
6	Characteristics	5
7	Package outline	8
8	Revision history	9
9	Legal information	10
9.1	Data sheet status	10
9.2	Definitions	10
9.3	Disclaimers	10
9.4	Trademarks	11
10	Contact information	11

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2010.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 29 July 2010

Document identifier: BUJ100LR

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[NXP](#):

[BUJ100LR,126](#) [BUJ100LR,412](#)